NSN 5962-01-206-1988

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-206-1988 **Body Length:** 1.111 inches **Body Width:** Between 0.350 inches and 0.410 inches **Body Height:** Between 0.155 inches and 0.210 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **End Application:** Ea-6b acft **Features Provided:** Electrostatic sensitive and schottky and programmed and bipolar and w/enable and 3-state output and asynchronous and synchronous and monolithic **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Case Outline Source And Designator:** D-7 mil-m-38510 **Current Rating Per Characteristic:** 185.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -0.5 volts power source and 7.0 volts power source **Memory Device Type:** Prom **Terminal Type And Quantity:** 22 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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